MOSFET – Power, N-Channel with ESD Protection, SOT-723

20 V, 285 mA

NTK3043N

$V_{(BR)DSS}$	$R_{DS(on)}$ TYP	I_D Max
20 V	1.5 Ω @ 4.5 V	285 mA
	2.4 Ω @ 2.5 V	
	5.1 Ω @ 1.8 V	
	6.8 Ω @ 1.65 V	

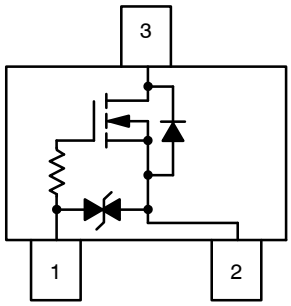
Features

- Enables High Density PCB Manufacturing
- 44% Smaller Footprint than SC-89 and 38% Thinner than SC-89
- Low Voltage Drive Makes this Device Ideal for Portable Equipment
- Low Threshold Levels, $V_{GS(TH)}$ < 1.3 V
- Low Profile (< 0.5 mm) Allows It to Fit Easily into Extremely Thin Environments such as Portable Electronics
- Operated at Standard Logic Level Gate Drive, Facilitating Future Migration to Lower Levels Using the Same Basic Topology
- These are Pb-Free and Halogen-Free Devices

Applications

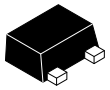
- Interfacing, Switching
- High Speed Switching
- Cellular Phones, PDAs

Top View



1 - Gate
2 - Source
3 - Drain

MARKING DIAGRAM



SOT-723
CASE 631AA
STYLE 5



KA = Device Code
M = Date Code

MAXIMUM RATINGS (T_J = 25 °C unless otherwise stated)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V_{DSS}	20	V
Gate-to-Source Voltage			V_{GS}	±10	V
Continuous Drain Current (Note 1)	Steady State	T_A = 25 °C	I_D	255	mA
		T_A = 85 °C		185	
	t ≤ 5 s	T_A = 25 °C		285	
Power Dissipation (Note 1)	Steady State	T_A = 25 °C	P_D	440	mW
	t ≤ 5 s			545	
Continuous Drain Current (Note 2)	Steady State	T_A = 25 °C	I_D	210	mA
		T_A = 85 °C		155	
Power Dissipation (Note 2)		T_A = 25 °C	P_D	310	mW
Pulsed Drain Current	t_p = 10 μs		I_{DM}	400	mA
Operating Junction and Storage Temperature			T_J, T_{STG}	−55 to 150	°C
Source Current (Body Diode) (Note 2)			I_S	286	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 seconds)			T_L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces)
2. Surface-mounted on FR4 board using the minimum recommended pad size.

ORDERING INFORMATION

Device	Package	Shipping†
NTK3043NT1G	SOT-723*	4000 / Tape & Reel
NTK3043NT5G	SOT-723*	8000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

* These packages are inherently Pb-Free.

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THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient – Steady State (Note 3)	$R_{\theta JA}$	280	°C/W
Junction-to-Ambient – t = 5 s (Note 3)	$R_{\theta JA}$	228	
Junction-to-Ambient – Steady State Minimum Pad (Note 4)	$R_{\theta JA}$	400	

3. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces)
4. Surface-mounted on FR4 board using the minimum recommended pad size.

ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise specified)

Parameter	Test Condition		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V_{GS} = 0 V, I_D = 100 μA		$V_{(BR)DSS}$	20			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	I_D = 100 μA, Reference to 25 °C		$V_{(BR)DSS}/T_J$		27		mV/°C
Zero Gate Voltage Drain Current	V_{GS} = 0 V, V_{DS} = 16 V	T_J = 25 °C	I_{DSS}			1	μA
		T_J = 125 °C				10	
Gate-to-Source Leakage Current	V_{DS} = 0 V, V_{GS} = ±5 V		I_{GSS}			1	μA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V_{GS} = V_{DS}, I_D = 250 μA		$V_{GS(TH)}$	0.4		1.3	V
Gate Threshold Temperature Coefficient			$V_{GS(TH)}/T_J$		–2.4		mV/°C
Drain-to-Source On Resistance	V_{GS} = 4.5V, I_D = 10 mA		$R_{DS(ON)}$		1.5	3.4	Ω
	V_{GS} = 4.5V, I_D = 255 mA				1.6	3.8	
	V_{GS} = 2.5 V, I_D = 1 mA				2.4	4.5	
	V_{GS} = 1.8 V, I_D = 1 mA				5.1	10	
	V_{GS} = 1.65 V, I_D = 1 mA				6.8	15	
Forward Transconductance	V_{DS} = 5 V, I_D = 100 mA		g_{FS}		0.275		S
Gate Resistance	T_A = 25 °C		R_G		2.2		kΩ
CHARGES, CAPACITANCES AND GATE RESISTANCE							
Input Capacitance	V_{GS} = 0 V, f = 1 MHz, V_{DS} = 10 V		C_{ISS}		11		pF
Output Capacitance			C_{OSS}		8.3		
Reverse Transfer Capacitance			C_{RSS}		2.7		
SWITCHING CHARACTERISTICS, VGS= 4.5 V (Note 4)							
Turn-On Delay Time	V_{GS} = 4.5 V, V_{DD} = 5 V, I_D = 10 mA, R_G = 6 Ω		$t_{d(ON)}$		13		ns
Rise Time			t_r		15		
Turn-Off Delay Time			$t_{d(OFF)}$		94		
Fall Time			t_f		55		
DRAIN-SOURCE DIODE CHARACTERISTICS							
Forward Diode Voltage	V_{GS} = 0 V, I_S= 286 mA	T_J = 25 °C	V_{SD}		0.83	1.2	V
		T_J = 125 °C			0.69		
Reverse Recovery Time	V_{GS} = 0 V, V_{DD} = 20 V, dISD/dt = 100 A/μs, I_S = 286 mA		t_{RR}		9.1		ns
Charge Time			t_a		7.1		
Discharge Time			t_b		2.0		
Reverse Recovery Charge			Q_{RR}		3.7		nC

5. Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%
6. Switching characteristics are independent of operating junction temperatures

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TYPICAL PERFORMANCE CURVES

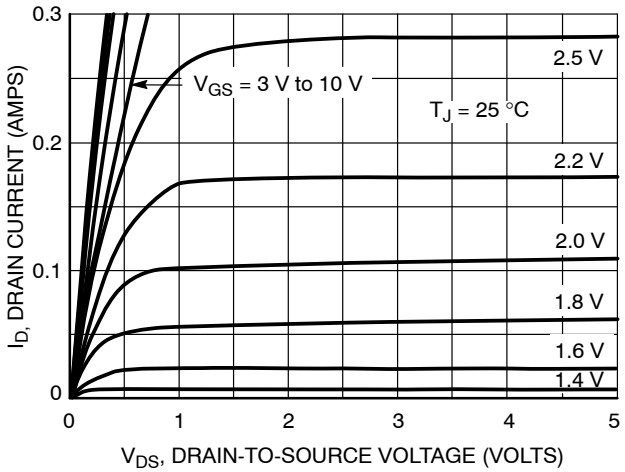


Figure 1. On-Region Characteristics

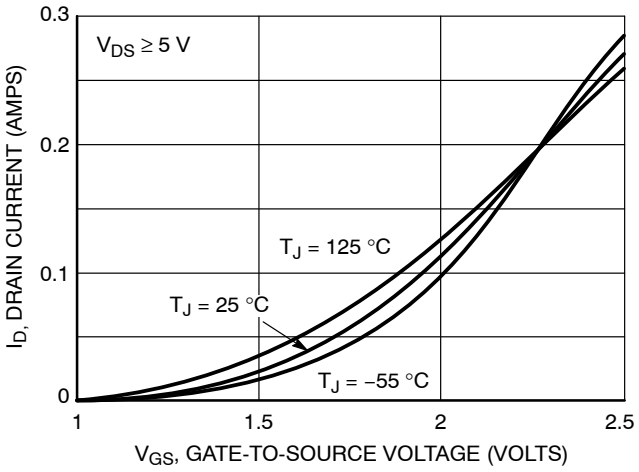


Figure 2. Transfer Characteristics

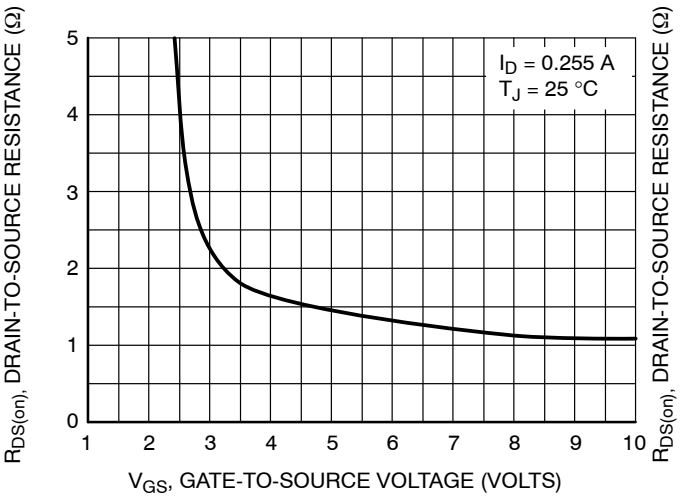


Figure 3. On-Resistance vs. Gate-to-Source Voltage

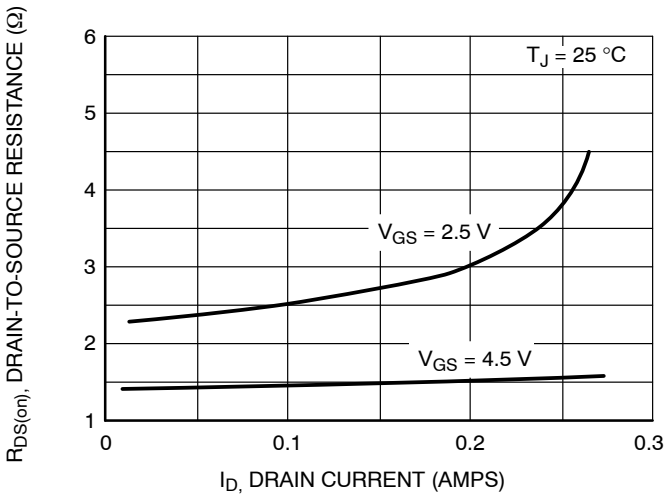


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

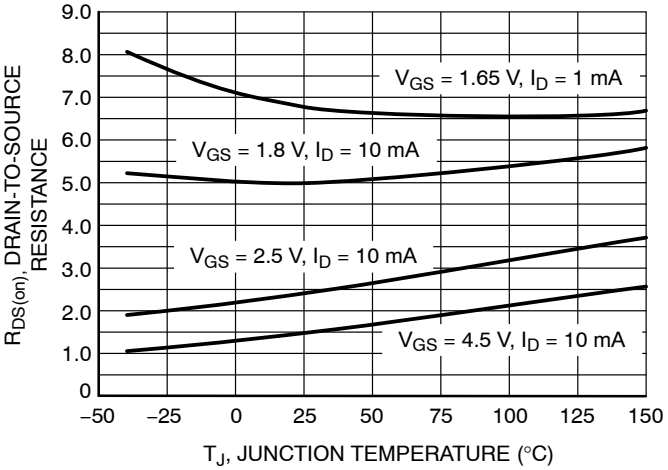


Figure 5. On-Resistance Variation with Temperature

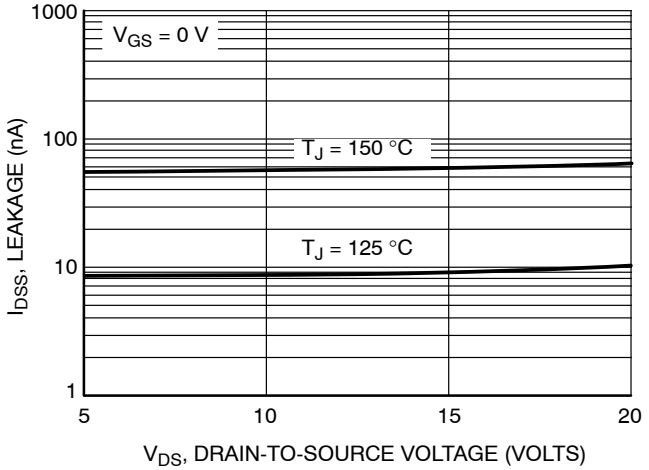


Figure 6. Drain-to-Source Leakage Current vs. Voltage

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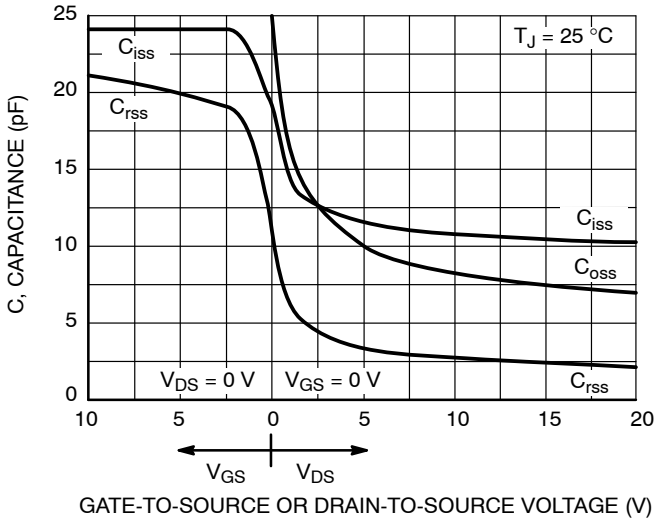


Figure 7. Capacitance Variation

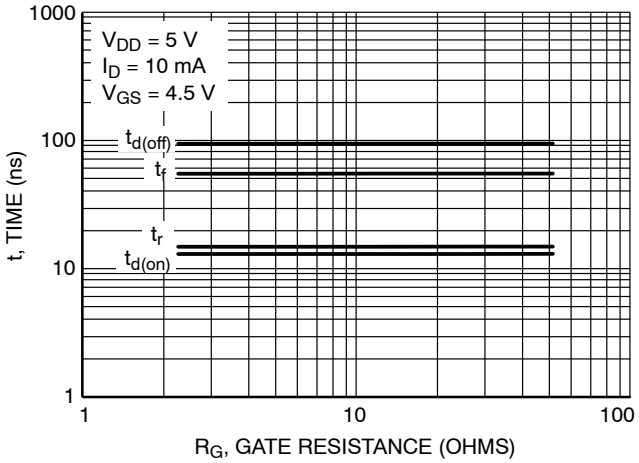


Figure 8. Resistive Switching Time Variation vs. Gate Resistance

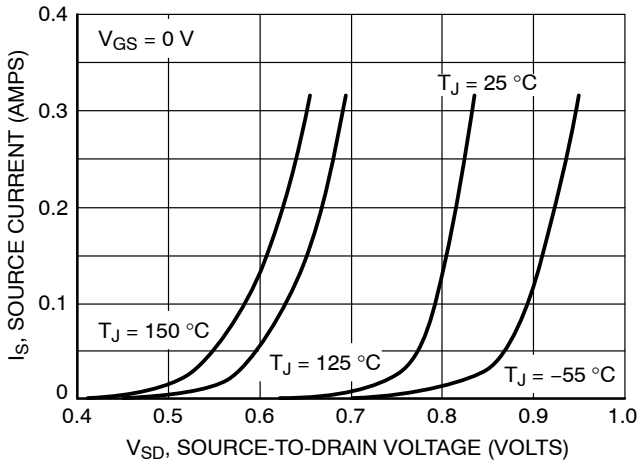


Figure 9. Diode Forward Voltage vs. Current

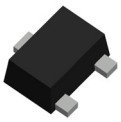
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REVISION HISTORY

6	Rebranded the document to **onsemi** format.	10/24/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

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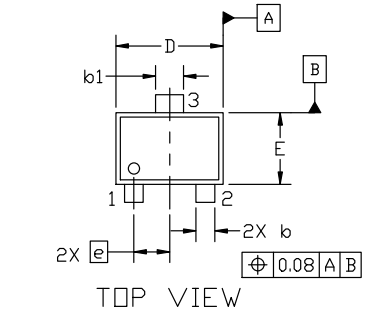


SOT−723 1.20x0.80x0.50, 0.40P
CASE 631AA
ISSUE E

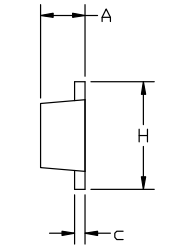
DATE 24 JAN 2024

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

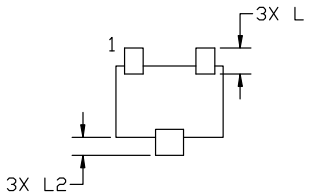
DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.45	0.50	0.55
b	0.15	0.21	0.27
b1	0.25	0.31	0.37
c	0.07	0.12	0.17
D	1.15	1.20	1.25
E	0.75	0.80	0.85
e	0.40 BSC		
H	1.15	1.20	1.25
L	0.29 REF		
L2	0.15	0.20	0.25



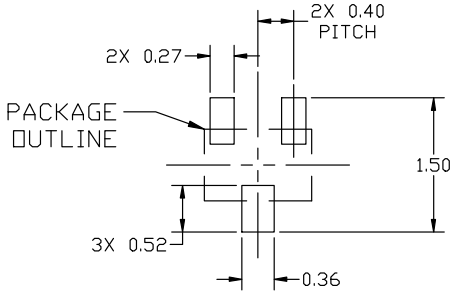
TOP VIEW



SIDE VIEW



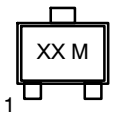
BOTTOM VIEW



RECOMMENDED MOUNTING
FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 2:
PIN 1. ANODE
2. N/C
3. CATHODE

STYLE 3:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 5:
PIN 1. GATE
2. SOURCE
3. DRAIN

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DESCRIPTION:	**SOT−723 1.20x0.80x0.50, 0.40P**	**PAGE 1 OF 1**

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